

RJH60M1DPE

600V - 8A - IGBT Application: Inverter R07DS0529EJ0300 Rev.3.00 May 25, 2012

Features

- Short circuit withstand time (8 µs typ.)
- Low collector to emitter saturation voltage $V_{CE(sat)} = 1.9$ V typ. (at $I_C = 8$ A, $V_{GE} = 15$ V, Ta = 25°C)
- Built in fast recovery diode (100 ns typ.) in one package
- Trench gate and thin wafer technology
- High speed switching $t_f=70 \text{ ns typ. (at $V_{CC}=300$ V, $V_{GE}=15$ V, $I_C=8$ A, $Rg=5$ Ω, inductive load)}$

Outline

RENESAS Package code: PRSS0004AE-B (Package name: LDPAK (S)-(1))

1. Gate 2. Collector 3. Emitter 4. Collector

Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

Item		Symbol	Ratings	Unit
Collector to emitter voltage / diode reverse voltage		V _{CES} / V _R	600	V
Gate to emitter voltage		V _{GES}	±30	V
Collector current	Tc = 25°C	I _C	16	A
	Tc = 100°C	I _C	8	A
Collector peak current		ic(peak) Note1	20	A
Collector to emitter diode forward current		i _{DF}	8	A
Collector to emitter diode forward peak current		i _{DF} (peak) Note1	32	Α
Collector dissipation		P _C Note2	52	W
Junction to case thermal resistance (IGBT)		θj-c Note2	2.38	°C/W
Junction to case thermal resistance (Diode)		θj-cd ^{Note2}	2.8	°C/W
Junction temperature		Tj	150	°C
Storage temperature		Tstg	-55 to +150	°C

Notes: 1. PW \leq 10 μ s, duty cycle \leq 1%

2. Value at Tc = 25°C

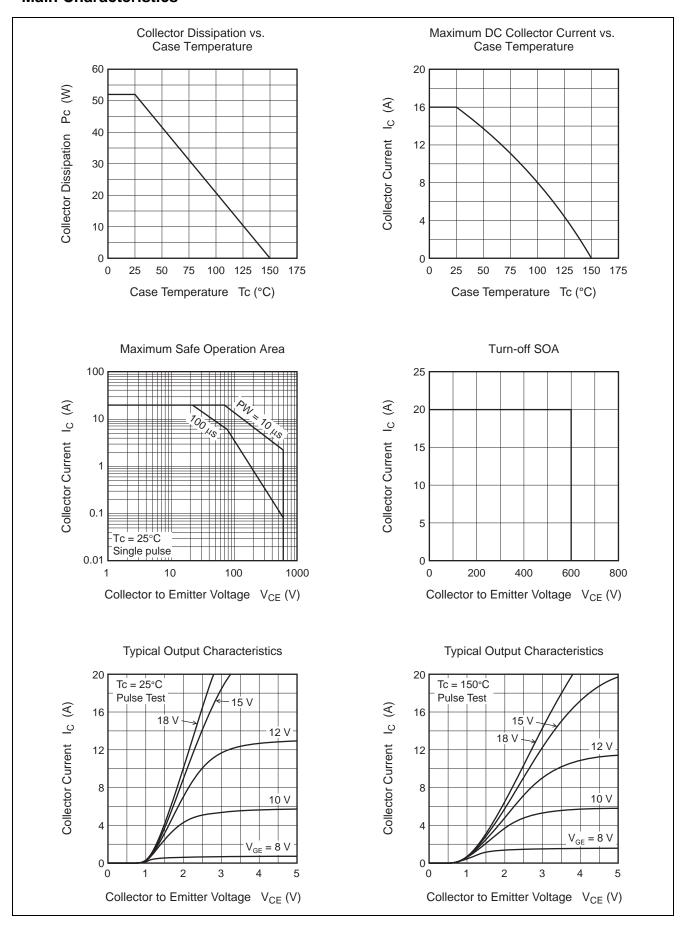
Electrical Characteristics

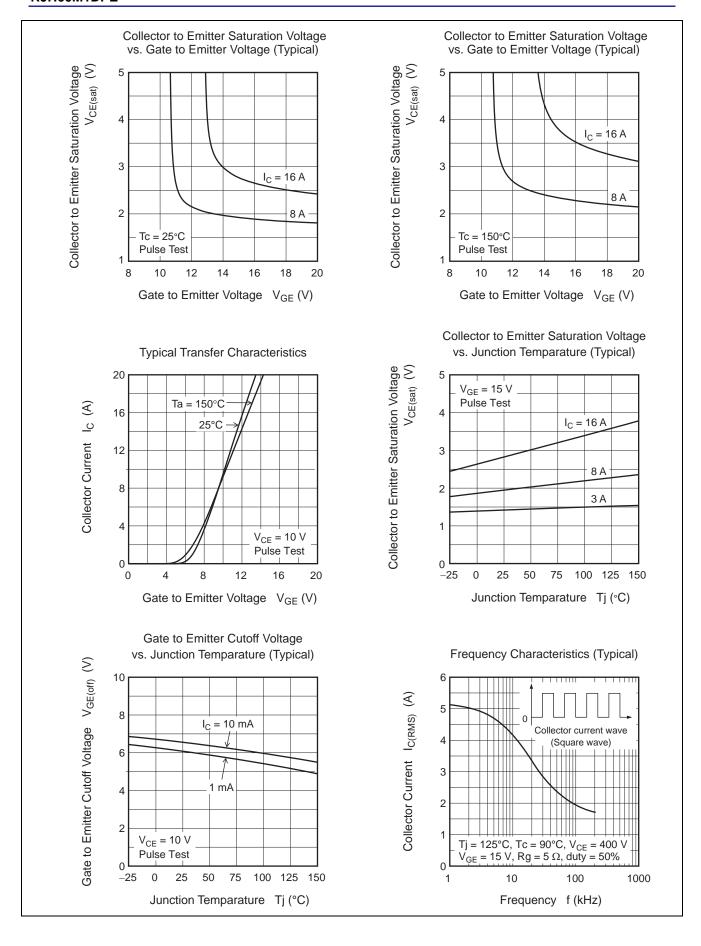
Item	Symbol	Min	Тур	Max	Unit	Test Conditions	
Collector to emitter breakdown voltage	V _{(BR)CES}	600	_	_	V	$I_C = 10 \mu A, V_{GE} = 0$	
Zero gate voltage collector current / Diode reverse current	I _{CES} / I _R	_	_	5	μА	$V_{CE} = 600 \text{ V}, V_{GE} = 0$	
Gate to emitter leak current	I _{GES}	_	_	±1	μΑ	$V_{GE} = \pm 30 \text{ V}, V_{CE} = 0$	
Gate to emitter cutoff voltage	$V_{GE(off)}$	5	_	7	V	$V_{CE} = 10 \text{ V}, I_{C} = 1 \text{ mA}$	
Collector to emitter saturation voltage	V _{CE(sat)}	_	1.9	2.4	V	$I_C = 8 \text{ A}, V_{GE} = 15 \text{ V}^{\text{Note3}}$	
	V _{CE(sat)}	_	2.8	_	V	$I_C = 16 \text{ A}, V_{GE} = 15 \text{ V}^{\text{Note3}}$	
Input capacitance	Cies	_	275	_	pF	V _{CE} = 25 V	
Output capacitance	Coes	_	25	_	pF	V _{GE} = 0 f = 1 MHz	
Reverse transfer capacitance	Cres	_	10	_	pF		
Total gate charge	Qg	_	20.5	_	nC	V _{GE} = 15 V V _{CE} = 300 V	
Gate to emitter charge	Qge	_	3	_	nC		
Gate to collector charge	Qgc	_	11.5	_	nC	I _C = 8 A	
Turn-on delay time	t _{d(on)}	_	30	_	ns	$V_{CC} = 300 \text{ V}$ $V_{GE} = 15 \text{ V}$ $I_{C} = 8 \text{ A}$ $Rg = 5 \Omega$ (Inductive load)	
Rise time	t _r	_	12	_	ns		
Turn-off delay time	t _{d(off)}	_	55	_	ns		
Fall time	t _f	_	70	_	ns		
Turn-on energy	Eon	_	0.08	_	mJ		
Turn-off energy	E _{off}	_	0.09	_	mJ		
Total switching energy	E _{total}	_	0.17	_	mJ		
Short circuit withstand time	t _{sc}	6	8	_	μS	$Tc = 100 ^{\circ}C$ $V_{GE} \leq 360 \text{V}, V_{GE} = 15 \text{V}$	
FRD Forward voltage	V _F	_	1.1	1.5	V	I _F = 8 A ^{Note3}	
EDD #			400			1	

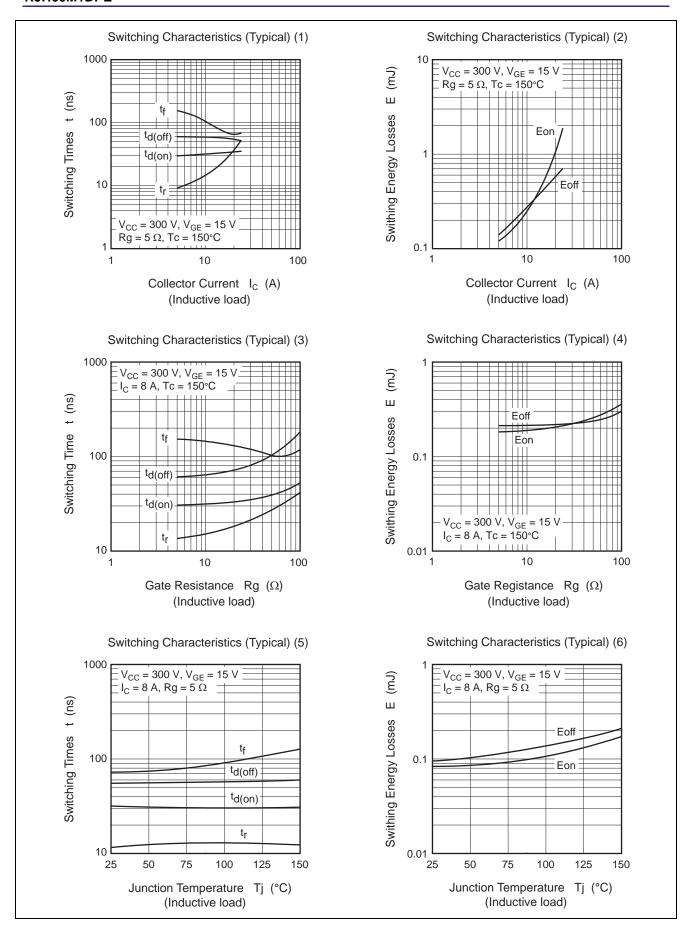
FRD Forward voltage	V_{F}		1.1	1.5	V	I _F = 8 A ^{Note3}
FRD reverse recovery time	t _{rr}	_	100	_	ns	I _F = 8 A
FRD reverse recovery charge	Qrr	_	0.18	_	μС	di _F /dt = 100 A/μs
FRD peak reverse recovery current	Irr	_	4.7		Α	

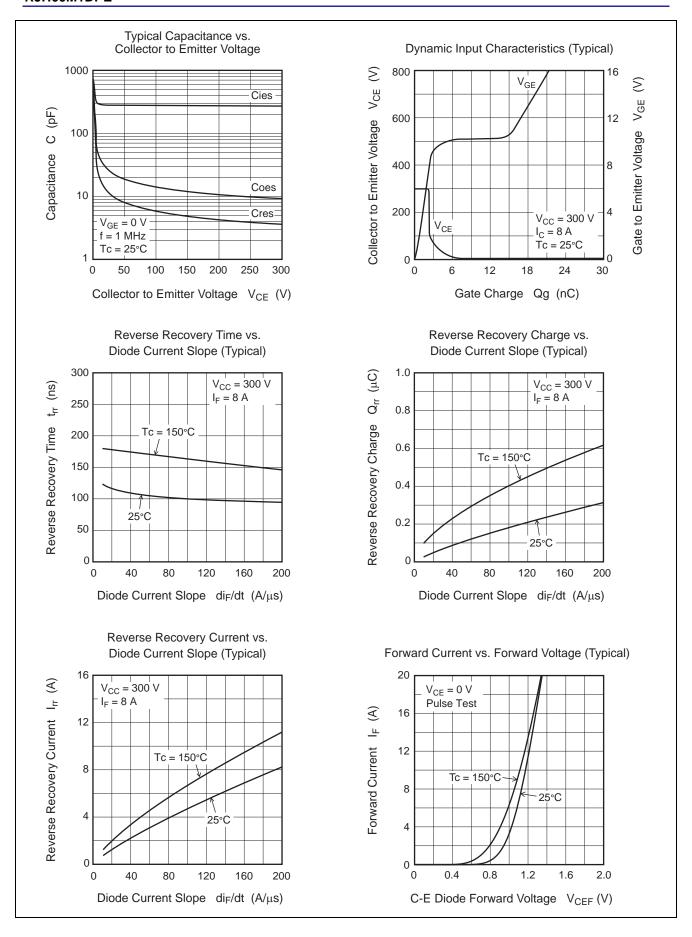
Notes: 3. Pulse test.

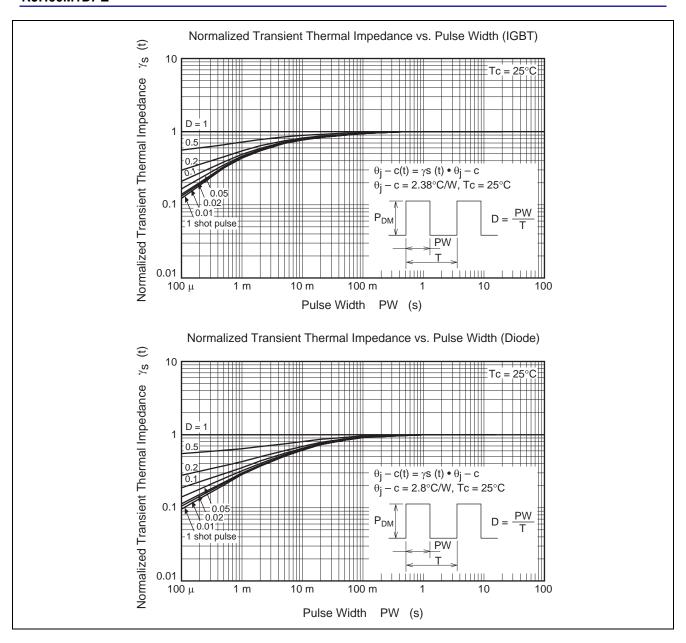
Main Characteristics

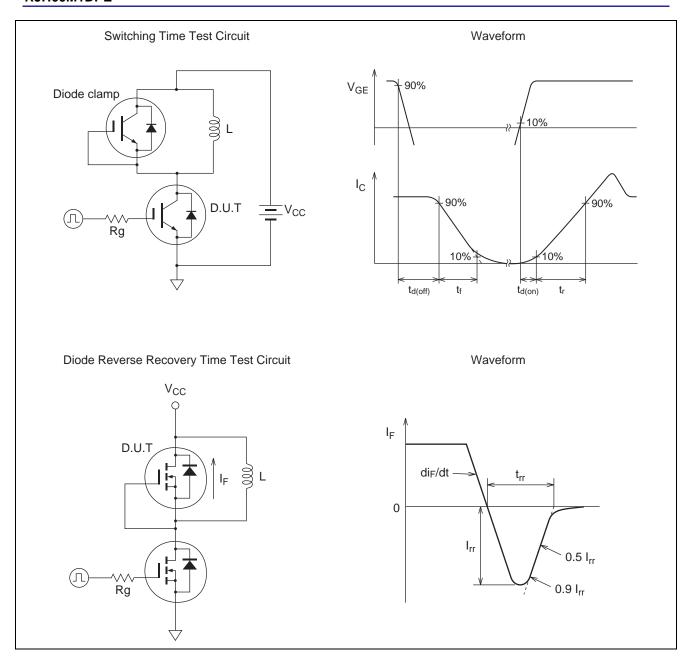




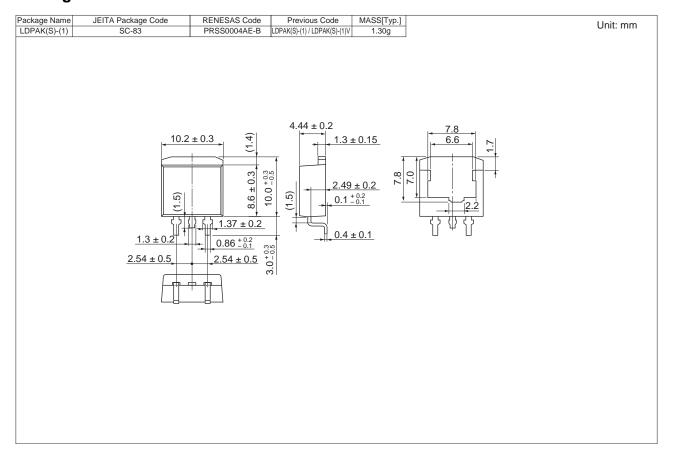








Package Dimension



Ordering Information

Orderable Part Number	Quantity	Shipping Container
RJH60M1DPE-00#J3	1000 pcs	Taping

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